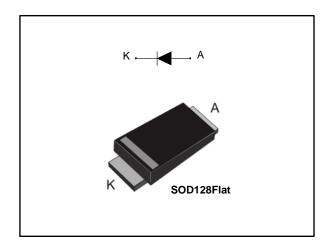


## STPS3H100AF

# High voltage power Schottky rectifier

Datasheet - production data



### **Description**

This high voltage Schottky barrier rectifier device is packaged in SOD128Flat and designed for high frequency miniature switched mode power supplies and for board DC to DC converters.

**Table 1: Device summary** 

Symbol	Value
I <sub>F(AV)</sub>	3 A
$V_{RRM}$	100 V
T <sub>j</sub> (max.)	175 °C
V <sub>F</sub> (typ.)	0.57 V

#### **Features**

- Negligible switching losses
- High junction temperature capability
- Low leakage current
- Good trade-off between leakage current and forward voltage drop
- Avalanche specification
- ECOPACK® compliant component

Characteristics STPS3H100AF

### 1 Characteristics

Table 2: Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Pa	Value	Unit	
V <sub>RRM</sub>	Repetitive peak reverse volltage	ge	100	V
I <sub>F(AV)</sub>	Average forward current	$T_L$ = 140 °C, $\delta$ = 0.5, square pulse	3	Α
1	Surge non repetitive forward $t_p = 10$ ms sinusoidal		75	_
IFSM	Current	t <sub>p</sub> = 8.3 ms sinusoidal	79	Α
P <sub>ARM</sub>	Repetitive peak avalanche power $t_p = 10 \ \mu s, T_j = 125 \ ^{\circ}C$		172	W
T <sub>stg</sub>	Storage temperature range		-65 to +175	°C
Tj	Operating junction temperature range <sup>(1)</sup>		-40 to +175	°C

#### Notes:

**Table 3: Thermal parameters** 

Symbol	Parameter	Max. value	Unit
$R_{th(j-l)}$	Junction to lead	16	°C/W

**Table 4: Static electrical characteristics** 

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 25 °C	V <sub>R</sub> = 100 V	-		1.5	μΑ
IR <sup>(*)</sup>		T <sub>j</sub> = 125 °C		-	0.6	1.7	mA
	V <sub>F</sub> <sup>(2)</sup> Forward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 3 A	-		0.76	
V (2)		T <sub>j</sub> = 125 °C		-	0.57	0.61	V
VFI-7 FOI		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 6 A	-		0.84	V
		T <sub>j</sub> = 125 °C		-	0.64	0.68	

#### Notes:

 $^{(1)}\text{Pulse}$  test:  $t_p$  = 5 ms,  $\delta$  < 2%

To evaluate the conduction losses use the following equation:

$$P = 0.54 \text{ x } I_{F(AV)} + 0.023 \text{ x } I_{F^2(RMS)}$$

For more information, please refer to the following application notes related to the power losses.

- AN604 (Calculation of conduction losses in a power rectifier)
- AN4021 (Calculation of reverse losses in a power diode)

 $<sup>^{(1)}(</sup>dP_{tot}/dT_j) < (1/R_{th(j-a)}) \ condition \ to \ avoid \ thermal \ runaway \ for \ a \ diode \ on \ its \ own \ heatsink.$ 

 $<sup>^{(2)}</sup>$ Pulse test:  $t_p$  = 380  $\mu$ s,  $\delta$  < 2%

STPS3H100AF Characteristics

### 1.1 Characteristics (curves)

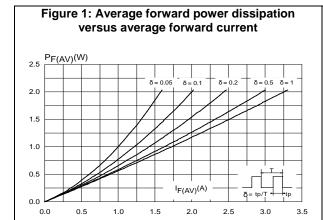


Figure 2: Average forward current versus ambient temperature (δ = 0.5)

12 | F(AV)(A) |
10 | R<sub>(h(j-4)</sub> = R<sub>(h(j-4)</sub> |
10 |

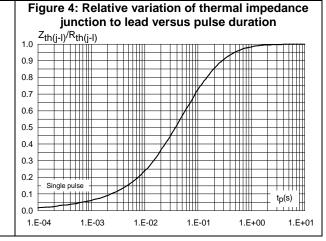
Figure 3: Normalized avalanche power derating versus pulse duration (T<sub>j</sub> = 125 °C)

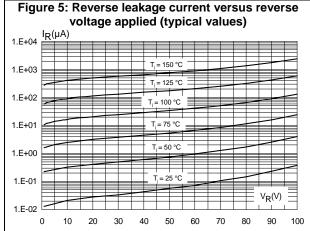
PARM(10 µS)

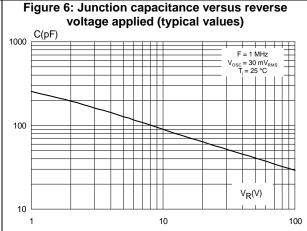
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1 10 100 1000







Characteristics STPS3H100AF

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Figure 7: Forward voltage drop versus forward

versus copper surface under each lead (typical values) R<sub>th(j-a)</sub>(°C/W) SOD128-Flat 150 100 Epoxy printed board FR4, e<sub>Cu</sub> = 35 μm 0.5 0.0 1.0 1.5 2.0 2.5 3.0 3.5 4.0 4.5 5.0

Figure 8: Thermal resistance junction to ambient

STPS3H100AF Package information

## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

- Epoxy meets UL94, V0
- Lead-free package

### 2.1 SOD128Flat package information

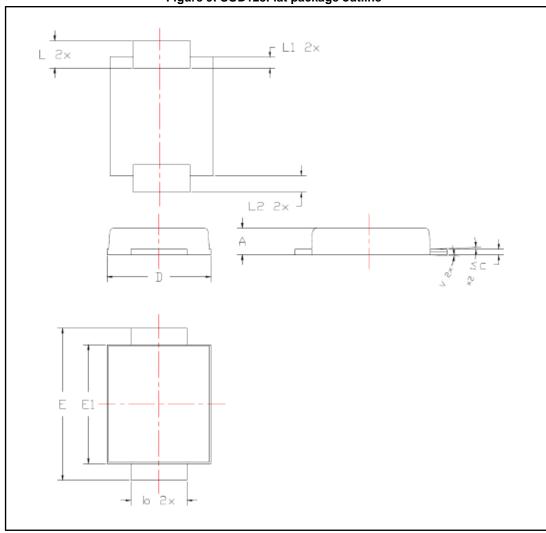


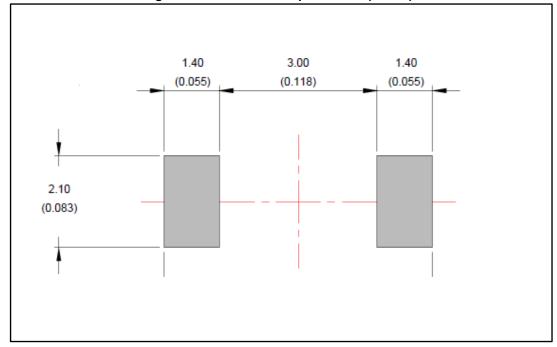
Figure 9: SOD128Flat package outline

577

Table 5: SOD128Flat package mechanical data

	Dimensions			
Ref.	Millimeters		Inc	hes
	Min.	Max.	Min.	Max.
A	0.93	1.03	0.037	0.041
b	1.69	1.81	0.067	0.071
С	0.10	0.22	0.004	0.009
D	2.30	2.50	0.091	0.098
E	4.60	4.80	0.181	0.189
E1	3.70	3.90	0.146	0.154
L	0.55	0.85	0.026	0.033
L1	0.30 typ.		0.012	2 typ.
L2	0.45 typ.		0.018	3 typ.

Figure 10: SOD128Flat footprint in mm (inches)



STPS3H100AF Ordering information

# 3 Ordering information

**Table 6: Ordering information** 

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS3H100AF	3H100	SOD128Flat	26.4 mg	3000	Tape and reel

# 4 Revision history

Table 7: Document revision history

Date	Revision	Changes
01-Jul-2016	1	Initial release.

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